Huge Piezoelectric Response of LaN-based Superlattices

Minglang Hu, Chang Liu, Lee A. Burton, and Wei Ren*

ABSTRACT: We construct LaN-based artificial superlattices to investigate the ferroelectricity and piezoelectricity using the volume matching conditions of the parent components that soften the elastic constant $C_{33}$ and increase the piezoelectric modulus $d_{33}$. The proposed superlattice consists of LaN and YN (or LaN and ScN) buckled monolayers alternately arranged along the crystallographic $c$-direction. The structure of polar wurtzite (w-LaYN/w-LaScN) is both mechanically and dynamically stable, and the computed energy barrier makes the ferroelectric polarization switching possible. We show that the epitaxial strain can modify the spontaneous ferroelectric polarization as well as $d_{33}$. The LaN/YN superlattice exhibits a huge piezoelectric response in the unstrained state, due to their small $c/a$ value and extremely soft $C_{33}$. In addition, the epitaxial strain is revealed as effective control of the nature (indirect and direct) and value of the electronic band gap.

KEYWORDS: density functional theory (DFT), ferroelectric, piezoelectric, rare earth nitrides, heterostructure

INTRODUCTION

Piezoelectric materials can generate electric fields upon mechanical deformation and vice versa. Discovered by Pierre and Jacques Curie in tourmaline in 1880, they are widely used in modern technology. The well-known ferroelectric single crystal and polycrystalline lead zirconate titanate (PZT) based perovskites have high electromechanical coefficients and piezoelectric responses, making them suitable for microelectromechanical system (MEMS) and nanoelectromechanical system (NEMS) devices. The power output of such devices is proportional to the piezoelectric response, but it decreases as the dielectric constant ($\varepsilon$) increases. However, shortcomings such as toxicity (the element lead), high cost, and high $\varepsilon$ urge people to explore nontoxic, cheap, and high piezoelectric response materials.

Some metal nitrides have a noncentrosymmetric space group and contain the most abundant element in the atmosphere—nitrogen. The wurtzite (B4) structure w-AlN has shown great potential for application in complex sensing and mobile communication systems. Furthermore, w-AlN has an output power equivalent to PZT and an extremely high mechanical quality factor $Q$ value, making it a perfect candidate for various MEMS/NEMS devices. However, the pure w-AlN compound still has the major disadvantage of having a low piezoelectric modulus ($d_{33} = 4.11$ pC/N according to our computation).

Recently, Akiyama et al. discovered that the piezoelectric response of Sc-doped w-AlN was significantly enhanced. Compared with pure w-AlN, the $d_{33}$ of Sc$_{0.5}$Al$_{0.5}$N alloy increases dramatically (about 400%), which is the largest piezoelectric response of known tetrahedral semiconductors.

This is due to the strong change in the strain response of the internal coordinates of atoms caused by Sc-doping, such that it increases the piezoelectric constant $e_{33}$. The tremendous increase in $d_{33}$ is due to the flattening of the energy landscape caused by the competition between the parent wurtzite (w-) and hexagonal (h-) phases, which makes the elastic constant $C_{33}$ significantly softer. Tholander et al. studied the piezoelectric response of w-AlN, GaN, and InN mixed with ScN or YN at a ratio of 1:1 through first-principles calculations. They explained the piezoelectric enhancement and confirmed the potential energy flattening phenomenon that caused the elastic softening of the alloys. In addition, the volume matching condition for the effective identification of new piezoelectric materials was proposed. The alloys with closely matched parent component volumes have a flatter potential energy landscape and a higher $d_{33}$ increase. Jiang et al. investigated the effect of epitaxial strain on the energetic, structural, electrical, electronic, and optical properties of a 1 × 1 AlN/ScN superlattice using ab initio calculations. The results encourage people to use dissimilar materials to make superlattices to realize the optimization and control of functionalities. Noor-A-Alam et al. explored the ferroelectricity and large piezoelectric response of the AlN/ScN superlattice and found that polar w-AlScN has mechanical...
Figure 1. Schematic diagram of the structure of w-LaYN (a). The blue, green, and gray atoms are La, Y, and N, respectively. The full phonon dispersions of (b) w-LaScN and (c) w-LaYN.

and dynamic stability. Furthermore, they suggested that tensile strain is required to transform the wurtzite-derived structure into a hexagonal-derived structure so as to induce a large piezoelectric response.

We propose that even more wurtzite nitrides can be realized as excellent piezoelectric materials. For example, lanthanum (La) nitride was synthesized in a supercritical nitrogen fluid at high pressure and high temperature.12 Ghezali et al.13 further explored the ground state of the six structural phases of LaN using full-potential first-principles methods, including the wurtzite LaN to be discussed here. In this paper, we investigate the ground state structure of LaN and its dynamic stability, and confirm its wurtzite ground state to be isostructural to AlN, GaN, and InN, which makes it feasible to construct a LaN/YN (LaN/ScN) superlattice.14

■ COMPUTATIONAL DETAILS

We performed first-principles calculations on $1 \times 1$ LaN/YN, LaN/ScN, and other superlattices within the framework of density functional theory (DFT),15,16 as implemented in the Vienna Ab initio Simulation Package (VASP)17 using the projector augmented wave (PAW)18,19 method. The exchange–correlation interaction was treated within the generalized gradient approximation (GGA)20 parametrized by Perdew, Burke, and Ernzerhof (PBE).21 The PAW potential describes the $[\text{Kr}]$ 4d10 states of La, $[\text{Ne}]$ states of Sc and $[\text{Ar}]$ 3d10 states of Y as core states. A set of 6 × 6 × 4 k-point samplings are used for the Brillouin zone22 in the reciprocal space by the Monkhorst–Pack scheme.23 The cut-off energy is set to be 520 eV. In addition, all systems are relaxed completely until the Hellmann–Feynman forces on all atoms are no more than $10^{-3}$ eV/Å. The conjugate gradient algorithm is used to optimize the lattice parameters and internal coordinates of the structures to achieve the lowest energy configurations. By employing the residual minimization scheme, direct inversion in the iterative subspace (RMM-DIIS), the systems are geometrically optimized and the convergence for the total energy is set as $10^{-6}$ eV. The phonon dispersions, Born effective charges (BECs) $Z_{ij}$, piezoelectric constants $e_{ij}$ and elastic constants $C_{ij}$ are calculated using density functional perturbation theory (DFPT).24,25

■ RESULTS AND DISCUSSION

By comparing the energy of the five space groups of LaN (shown in Table S1), we find that the wurtzite phase has the lowest energy, which is consistent with the work of Ghezali et al.13 To assess its dynamic stability, we calculate the phonon dispersion of w-LaN (shown in Figure S1). There is no unstable imaginary mode in the phonon dispersion, which confirms that it is a stable ground structure. Therefore, it provides us a solid foundation to build $1 \times 1$ LaN/YN (LaYN) and LaN/ScN (LaScN) superlattices.

As shown in Figure 1a, the presently investigated LaYN (LaScN) superlattice has hexagonal parent compounds LaN and YN (ScN). The primitive lattice vectors of the direct Bravais lattice are

$$a_1 = \frac{1}{2} \begin{pmatrix} 1 & -x - \sqrt{3} \ y \end{pmatrix}$$

$$a_2 = \frac{1}{2} \begin{pmatrix} 1 & x + \sqrt{3} \ y \end{pmatrix}$$

$$a_3 = cz$$

Among them, $a$ (in-plane) and $c$ (out-of-plane) are two lattice parameters. $c/a$ is defined as the axial ratio. $x$, $y$, and $z$ are the unit vectors along the Cartesian axes. The primitive unit cell contains four atoms, namely, Y (Sc) and La located at $r_1$ and $r_2$ and two N atoms located at $r_3$ and $r_4$ with

$$r_1 = 0$$

$$r_2 = \frac{2}{3}a_1 + \frac{1}{3}a_2 + \frac{1}{2}a_3$$

$$r_3 = a_{Y(Sc)}a_3$$

$$r_4 = \frac{2}{3}a_1 + \frac{1}{3}a_2 + \frac{1}{2} + u_{La}a_3$$

The LaYN (LaScN) superlattice consists of LaN and YN (ScN) buckled monolayers, alternately arranged along the crystallographic c-direction. The quantities $a_{Y(Sc)}$ and $u_{La}$ are the dimensionless internal parameters, where $a_{Y(Sc)}$ is connecting the Y (Sc) and N atoms that are nearest neighbors along the $z$-axis, and the $u_{La}$ is binding La ions and the N atoms along $a_3$.

Table S2 shows the parameters of LaN, YN, LaYN, and LaScN superlattices. Since w-LaYN and w-LaScN are new structures, their mechanical stability are checked according to the standard of the hexagonal crystal structure:26 $C_{11} > C_{12}$,

$2C_{13} < C_{33}$ ($C_{11} + C_{12}$), $C_{44} > 0$, $C_{66} > 0$. Additionally, in the light of the elastic constants provided in Table S3, it can be seen that w-LaYN and w-LaScN are mechanically stable. The phonon dispersions of w-LaYN and w-LaScN are also calculated as shown in Figure 1b,c. There is no unstable imaginary mode in the phonon dispersions, which confirms that w-LaYN and w-LaScN are stable structures or structurally metastable. From the group theory analysis, there are nine optical modes at $\Gamma$ with irreducible representation: $\Gamma_{\text{opt}} = 3E +$
3A_{1g}, where E modes are doubly degenerate. The L, M, and H in Figure 1bc are used for labeling the low, medium, and high frequencies for both E and A_{1g} modes. The A_{1g} modes represent the atomic vibration along the c-direction, while the atoms vibrate in-plane for the E modes. Three A_{1g} modes along the Γ–A direction in the first Brillouin zone are shown in Figure S2a.

Note that the wurtzite structure has a 6mm point group in the ideal form. The c/a ratios of w-LaYN and w-LaScN are both lower than the ideal value, leading to spontaneous polarization in the [0001] direction. Our calculated spontaneous polarization along the c-direction, P_c, for w-LaYN (w-LaScN) is 0.73 C/m^2 (1.07 C/m^2), with an energy barrier of 0.15 eV (0.53 eV). The studied superlattices both have spontaneous polarization larger than BaTiO_3 (~0.25 C/m^2) and even comparable with PbTiO_3 (~0.88 C/m^2). Therefore, w-LaYN should be a promising candidate for ferroelectricity, while the energy barrier of w-LaScN might be somewhat high for practical ferroelectric devices. (More calculational details of ferroelectric polarization can be found in the Supporting Information.)

As is well known, ferroelectric materials should be able to generate piezoelectric responses but not vice versa. We find that the ε_{33} values of LaN-based superlattices are larger than that of w-LaN. A similar situation occurs in other ternary alloys as well, and our superlattices here are alloys with a specific composition and configuration. We calculate the properties of w-AlN, GaN, InN, and their superlattices to confirm their conclusion (shown in Table 1). The C_{33} and ε_{33} results of AlN are 1.41, 0.45, and 1.2, respectively.

Table 1. Piezoelectric Constant ε_{33}, Elastic Constant C_{33}, and Piezoelectric Modulus d_{33} for Parent Binaries and 1 × 1 Superlattices with ScN and YN

<table>
<thead>
<tr>
<th>Material</th>
<th>ε_{33} (C/m^2)</th>
<th>ε_{33}/σ_{33}</th>
<th>C_{33} (GPa)</th>
<th>C_{33}/C_{31}</th>
<th>d_{33} (pC/N)</th>
<th>Δd_{33} (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>AlN</td>
<td>1.46</td>
<td>354.89</td>
<td>4.11</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>GaN</td>
<td>0.44</td>
<td>358.58</td>
<td>1.22</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>InN</td>
<td>0.87</td>
<td>205.73</td>
<td>4.21</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>LaN</td>
<td>1.78</td>
<td>82.98</td>
<td>21.45</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>AlScN</td>
<td>1.78</td>
<td>198.02</td>
<td>0.56</td>
<td>8.98</td>
<td>4.87 (118%)</td>
<td></td>
</tr>
<tr>
<td>AlYN</td>
<td>1.20</td>
<td>211.21</td>
<td>0.60</td>
<td>5.70</td>
<td>1.59 (39%)</td>
<td></td>
</tr>
<tr>
<td>GaScN</td>
<td>1.33</td>
<td>201.95</td>
<td>0.56</td>
<td>6.59</td>
<td>5.37 (440%)</td>
<td></td>
</tr>
<tr>
<td>GaYN</td>
<td>1.12</td>
<td>175.24</td>
<td>0.49</td>
<td>6.41</td>
<td>5.19 (425%)</td>
<td></td>
</tr>
<tr>
<td>InScN</td>
<td>1.52</td>
<td>163.36</td>
<td>0.79</td>
<td>9.29</td>
<td>5.08 (121%)</td>
<td></td>
</tr>
<tr>
<td>InYN</td>
<td>1.72</td>
<td>119.61</td>
<td>0.58</td>
<td>14.34</td>
<td>10.13 (241%)</td>
<td></td>
</tr>
<tr>
<td>LaScN</td>
<td>1.81</td>
<td>116.31</td>
<td>1.40</td>
<td>15.59</td>
<td>−5.86 (−27%)</td>
<td></td>
</tr>
<tr>
<td>LaYN</td>
<td>2.53</td>
<td>75.70</td>
<td>0.91</td>
<td>33.38</td>
<td>11.93 (56%)</td>
<td></td>
</tr>
</tbody>
</table>

The ε_{33} values of the AIYN superlattice are lower than that of the parent nitride and the C_{33} value of the LaScN superlattice is higher than that of the parent nitride. In contrast, the other superlattices have higher ε_{33} and lower C_{33} than their parent nitride, resulting in an enhancement in piezoelectric modulus d_{33}. This proves the volume matching condition to establish enhanced piezoelectricity. It is worth noting that the volumes of the parent nitrides of AIYN and LaScN superlattices are extremes (i.e., maximal YN + minimal AlN or minimal ScN + maximal LaN), where the d_{33} value of LaScN is reduced, as shown in Figure 2. Furthermore, we can find that as V_A/V_B approaches 1, the d_{33} value increases. While AIYN superlattice’s V_A/V_B = 0.61, it only increases the d_{33} value by 1.59 pC/N; LaScN superlattice’s V_A/V_B = 1.62 even decreases the d_{33} value by 5.86 pC/N. We recommend that a parent nitride with a larger d_{33} value should be used to establish the superlattice. Although the Δd_{33} (%) values of GaScN, GaYN, and InYN superlattices are relatively large, the superlattice d_{33} is still small overall due to the small d_{33} value of the parent nitride. Yet, the LaYN superlattice does not have this disadvantage since LaN already possesses a large d_{33} value and incorporating YN could further increase it by 56%.

To understand the piezoelectric behavior from a microscopic perspective, ε_{33} is usually decomposed into “clamped ion” and “internal strain” contributions:

ε_{33} = ε_{33,c} + ε_{33,i}

The clamped-ion ε_{33,c} is evaluated without allowing additional relaxation of the relative atomic coordinates that would be induced by the strain. In contrast, the internal strain ε_{33,i} only measures the contribution of these internal deformations to the piezoelectric response. We find that ε_{33,i} increases with increasing lattice parameters from the compressive to tensile strains. On the other hand, ε_{33,c} is positively related to the epitaxial strain of −4−1% (1.75%) and negatively related to the tensile epitaxial strain of 1% (1.75%) to 3% for the LaYN (LaScN) superlattice in Figure 3a,b. We also show the relation trend of ε_{33} and c/a values in Figure S3 to explain this increase under the epitaxial strain of −4−1.5% (1%). Momida et al. discovered the effect of lattice parameters on piezoelectric constants in wurtzite materials. According to the energy potential energy landscapes in Figure 3c,d, we can find that when the c/a value becomes lower than about 1.35 (1.42), the small-volume LaYN (LaScN) superlattice tends to have the hexagonal structure, which also leads to a decrease in ε_{33}. Although for LaYN, ε_{33} increases from zero epitaxial to 1.25% tensile strain, we find that C_{33} is minimum at zero strain, which is different from the cases of other superlattices. The c/a = 1.403 of the LaYN superlattice without strain is small, making the energy landscape more flattened by the competition between the parent wurtzite and hexagonal phases. Moreover, ε_{33} increases at 0−1.75% epitaxial strain and C_{33} is minimum at 1.5% epitaxial strain for the LaScN superlattice.

The d_{33} of the hexagonal structure is defined as:

d_{33} = \frac{ε_{33} - \frac{2ε_{33}}{C_{33}}ε_{31}}{C_{33}} = \frac{2ε_{33}}{C_{33}C_{12}}

in which the in-plane parameters ε_{31}, C_{11}, C_{12}, and C_{33} can be fixed so that d_{33} is approximately equal to ε_{33}/C_{33}. w-LaYN has a huge d_{33} (33.38 pC/N) under no strain, although the epitaxial tensile strain does not increase the d_{33} value, while it effectively reduces the spontaneous ferroelectric polarization. Therefore, w-LaYN is an ideal piezoelectric material in the normal state under no applied strain. The maximum d_{33} (19.27 pC/N) is at 1.75% epitaxial strain for the LaScN superlattice.

Interestingly, the epitaxial strain also acts as effective control for the nature (indirect and direct) and value of the electronic band gap as shown in Figure 4. Under all strains, the contribution of the conduction band minimum (CBM) comes from the s orbitals of all atoms, while the contribution of the valence band maximum (VBM) varies with strain, leading to a change in the trend of the band gap value and nature. Under
3% epitaxial strain, the VBM is mainly contributed by the $p_z$ orbital of $N_{La}$ (the $N$ connected with La along the $z$-axis), which is similar to the paraelectric phase structure when we analyzed the electronic origin of ferroelectricity. Under large epitaxial tensile strain, the superlattice changes from the ferroelectric phase to the paraelectric phase, which causes the $p_z$ orbital of $N_{La}$ to hybridize with the $d_{z^2}$ of La. Under small tensile strain or compressive strain, the VBM is contributed by other $N$ $p_x$ or $p_y$ orbitals. For the LaYN superlattice under an epitaxial tensile strain of 2–3%, the direct band gap could be present at the $\Gamma$ point.

It is worth mentioning that, in realistic experiments, an appropriate epitaxial strain may be induced by growing nitrides on another nitride substrate or adjusted by doping the nitride substrate. Recently, high-quality artificial nitride samples with designed epitaxial strain have been achieved. In addition, there may also be suitable parent components in metal oxides to construct superlattices, such as ZnO and MgO. In fact, piezoelectric ZnO/MgO films have been prepared in experiments, and related measurements have been reported.

**CONCLUSIONS**

In summary, from the ground state wurtzite structure of LaN, we have constructed wurtzite-like $1 \times 1$ LaN-based artificial superlattices that are both mechanically and dynamically stable.
and show spontaneous ferroelectric polarization. The volume matching condition of the parent components allows the softening of the elastic constant $C_{33}$ and increases the piezoelectric modulus $d_{33}$, resulting in a huge $d_{33}$ value of w-LaYN. In addition, epitaxial tensile strain is found to introduce a significant change in the spontaneous ferroelectric polarization and $d_{33}$ as well. The strain is also demonstrated to effectively control the nature (indirect and direct) and value of the electronic band gap. Our results provide guidance for designing nitride superlattice ferroelectric and piezoelectric materials.

## ASSOCIATED CONTENT

* Supporting Information

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acsami.0c14969.

- Energy comparison of different structures of LaN (Table S1); related structural parameters and physical properties discussed in the article (Tables S2 and S3); dynamic stability prediction of LaN from phonon spectra (Figure S1); vibration mode of $A_1$ and phonon dispersion with considering the nonanalytic correction term (Figure S2); $c/a$ versus lattice constant ratio ($c/a$) of the LaN-based superlattices (Figure S3); ferroelectric energy barrier and polarization value of the LaN-based superlattices (Figure S4); phonon and electronic origin of ferroelectricity (Figures S5 and S6) (PDF)

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**Notes**

The authors declare no competing financial interest.

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**Figure 4.** (a) Nature (indirect and direct) and value of the electronic band gap of LaN-based superlattices as a function of epitaxial strain for the epitaxial strain ranging between $-4$ and $3\%$. The projected energy band structures of the LaScN superlattice change with the epitaxial strain values of (b) $-4.00\%$ and (c) $3.00\%$. The LaYN superlattice changes with the epitaxial strain values of (d) $-4.00\%$, (e) $1.00\%$, and (f) $3.00\%$. 

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